VS-50PF(R)...(W) High Voltage Series

Vishay Semiconductors

Standard Recovery Diodes, Generation 2 DO-5 (Stud Version), 50 A



www.vishay.com

| PRIMARY CHARACTERISTICS | | | | | |
|-------------------------|-----------------|--|--|--|--|
| I _{F(AV)} 50 A | | | | | |
| Package | DO-5 (DO-203AB) | | | | |
| Circuit configuration | Single | | | | |

FEATURES

- High surge current capability
- · Designed for a wide range of applications
- Stud cathode and stud anode version
- Wire version available
- Low thermal resistance
- Designed and qualified for multiple level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

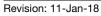
TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- Welding
- Any high voltage input rectification bridge

| MAJOR RATINGS AND CHARACTERISTICS | | | | | |
|-----------------------------------|-----------------|--------------|------------------|--|--|
| PARAMETER | TEST CONDITIONS | VALUES | UNITS | | |
| | | 50 | А | | |
| I _{F(AV)} | T _C | 128 | °C | | |
| I _{F(RMS)} | | 78 | А | | |
| I _{FSM} | 50 Hz | 570 | | | |
| | 60 Hz | 595 | A | | |
| l ² t | 50 Hz | 1600 | A ² s | | |
| 1-1 | 60 Hz | 1450 | A-5 | | |
| V _{RRM} | Range | 1400 to 1600 | V | | |
| TJ | | -55 to +160 | °C | | |

ELECTRICAL SPECIFICATIONS

| VOLTAGE RATINGS | | | | | | |
|-------------------|-----------------|--|--|--|--|--|
| TYPE NUMBER | VOLTAGE CODE | V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V | V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V | I _{RRM} MAXIMUM AT T _J = 150 °C mA | | |
| VS-50PF(R)(W) 140 | | 1400 | 1650 | 4.5 | | |
| V3-50FF(N)(VV) | 160 | 1600 | 1900 | 4.5 | | |



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| FORWARD CONDUCTION | | | | | | |
|--|---------------------|---|-------------------------------------|--|--------|------------------|
| PARAMETER | SYMBOL | TEST CONDITIONS | | | VALUES | UNITS |
| Maximum average forward current | I = | 180° conduc | tion, half sine wave | | 50 | А |
| at case temperature | I _{F(AV)} | | tion, nan sine wave | | 128 | °C |
| Maximum RMS forward current | I _{F(RMS)} | | | | 78 | А |
| | | t = 10 ms | No voltage | | 570 | A |
| Maximum peak, one cycle forward, | I | t = 8.3 ms | reapplied | Sinusoidal half wave, initial T _J = 150 °C | 595 | |
| non-repetitive surge current | IFSM | t = 10 ms | 100 % V _{RRM} reapplied | | 480 | |
| | | t = 8.3 ms | | | 500 | |
| | | t = 10 ms | No voltage | | 1600 | A ² s |
| Maximum I ² t for fusing | l ² t | t = 8.3 ms | reapplied | | 1450 | |
| Maximum int for fusing | | t = 10 ms | 100 % V _{RRM} reapplied | | 1150 | |
| | | t = 8.3 ms | | | 1050 | |
| Maximum I ² \sqrt{t} for fusing | l²√t | t = 0.1 ms to 10 ms, no voltage reapplied | | | 16 000 | A²√s |
| Low level value of threshold voltage | V _{F(TO)} | (16.7 % x π x I _{F(AV)} < I < π x I _{F(AV)}), T _J = T _J maximum 0.77 | | | V | |
| Low level value of forward slope resistance | r _f | $(16.7 \% \text{ x } \pi \text{ x } _{F(AV)} < I < \pi \text{ x } _{F(AV)}), T_J = T_J \text{ maximum}$ 4.30 m Ω | | | mΩ | |
| Maximum forward voltage drop | V _{FM} | $I_{pk} = 125 \text{ A}, T_J = 25 \text{ °C}, t_p = 400 \ \mu \text{s}$ rectangular wave 1.50 V | | | V | |

| THERMAL AND MECHANICAL SPECIFICATIONS | | | | | |
|---|-----------------------------------|---|-----------------|---------------------|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -55 to 160 | °C | |
| Maximum thermal resistance, junction to case | R _{thJC} | DC operation | 0.51 | | |
| Thermal resistance, case to heatsink | R _{thCS} | Mounting surface, smooth, flat and greased 0.25 | | K/W | |
| Maximum allowable mounting torque (+0 %, -10 %) | | Not lubricated thread, tighting on nut ⁽¹⁾ | 3.4 (30) | N ⋅ m (lbf ⋅ in) | |
| | | Lubricated thread, tighting on nut ⁽¹⁾ | 2.3 (20) | | |
| | | Not lubricated thread, tighting on hexagon ⁽²⁾ | 4.2 (37) | | |
| | | Lubricated thread, tighting on hexagon ⁽²⁾ | 3.2 (28) | | |
| Approximate weight | | | 15.8 | g | |
| Approximate weight | | | 0.56 | oz. | |
| Case style | | See dimensions - link at the end of datasheet | DO-5 (DO-203AB) | | |

Notes

⁽¹⁾ Recommended for pass-through holes

⁽²⁾ Torque must be appliable only to hexagon and not to plastic structure, recommended for holed heatsink

| CONDUCTION ANGLE | SINUSOIDAL CONDUCTION | RECTANGULAR CONDUCTION | TEST CONDITIONS | UNITS | | |
|------------------|-----------------------|------------------------|---------------------|-------|--|--|
| 180° | 0.11 | 0.10 | | | | |
| 120° | 0.16 | 0.16 | | | | |
| 90° | 0.20 | 0.22 | $T_J = T_J$ maximum | K/W | | |
| 60° | 0.29 | 0.31 | | | | |
| 30° | 0.49 | 0.50 | | | | |

Note

• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

Revision: 11-Jan-18

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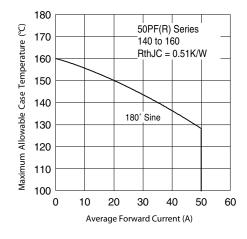


Fig. 1 - Current Ratings Characteristics

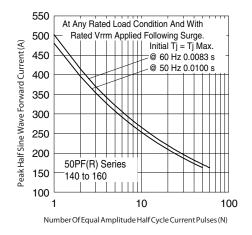


Fig. 2 - Maximum Non-Repetitive Surge Current

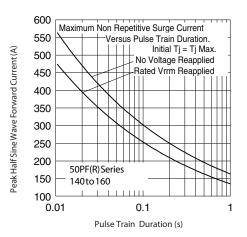


Fig. 3 - Maximum Non-Repetitive Surge Current

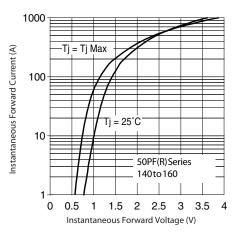


Fig. 4 - Forward Voltage Drop Characteristics

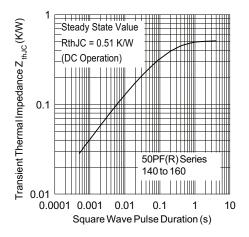


Fig. 5 - Thermal Impedance ZthJC Characteristics



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ORDERING INFORMATION TABLE

| Device code | vs- | 50 | PF | R | 160 | w |
|-------------|-----|------------------------|----------|-----------|----------------------|-----------|
| | | 2 | 3 | 4 | 5 | 6 |
| | 1 - | Vish | ay Sem | iconduc | tors pro | duct |
| | 2 - | - 50 = | standa | rd devic | e | |
| | 3 - | - PF = plastic package | | | | |
| | 4 - | • No | one = st | ud norm | nal polar | ity (cath |
| | | • R | = stud r | everse p | oolarity | (anode t |
| | 5 - | · Volt | age cod | le x 10 = | = V _{RRM} (| see Volt |
| | 6 - | • No | one = st | andard | terminal | |
| | | (se | ee dime | nsions f | or 50PF | (R) li |
| | | • W | = wire 1 | erminal | | |
| | | (se | ee dime | nsions f | or 50PF | (R)W - |

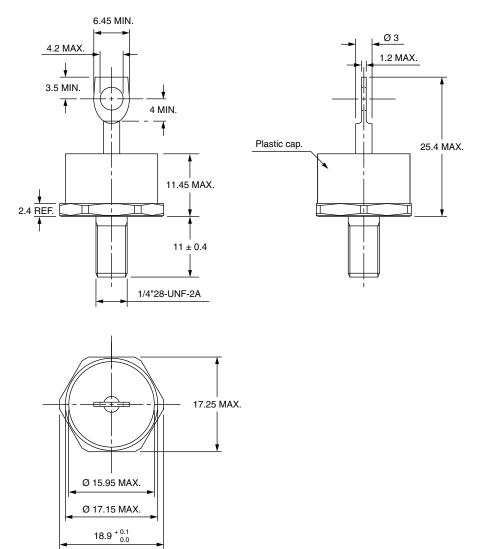
| LINKS TO RELATED DOCUMENTS | | | |
|----------------------------|--------------------------|--|--|
| Dimensions | www.vishay.com/doc?95345 | | |



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DO-203AB (DO-5) for 50PF(R)...(W), 80PF(R)...(W), and 95PF(R)...(W) Series

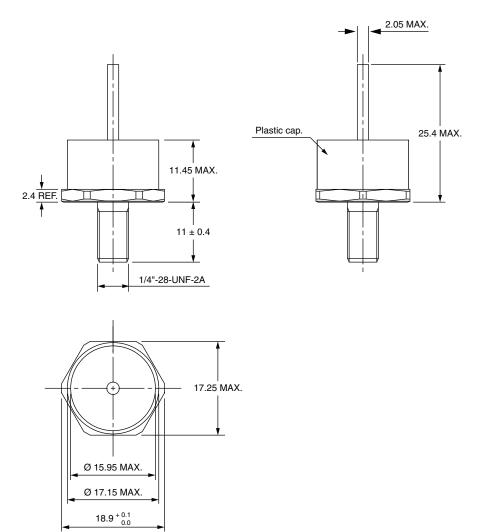
DIMENSIONS FOR 80PF(R), 50PF(R), AND 95PF(R) SERIES in millimeters





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DIMENSIONS FOR 80PF(R)...(W), 50PF(R)...(W), AND 95PF(R)...(W) SERIES in millimeters

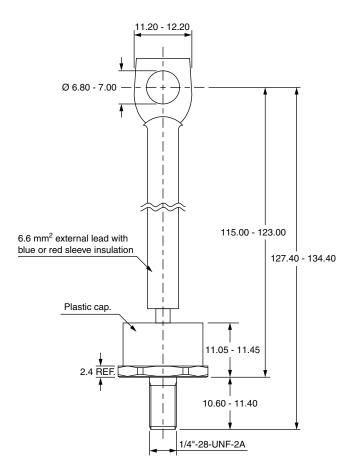


Outline Dimensions



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DIMENSIONS FOR 52PF(R), 82PF(R), AND 97PF(R) SERIES in millimeters





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